

TITLE: FLASH MEMORY CELL HAVING REDUCED LEAKAGE CURRENT INVENTOR(S): Sheung Hee Park, Richard M. Fastow, and Dong-Hyuk Ju USSN: 10/618,191 Attorney Docket #: AMD-H0534

REPLACEMENT SHEET

4/5

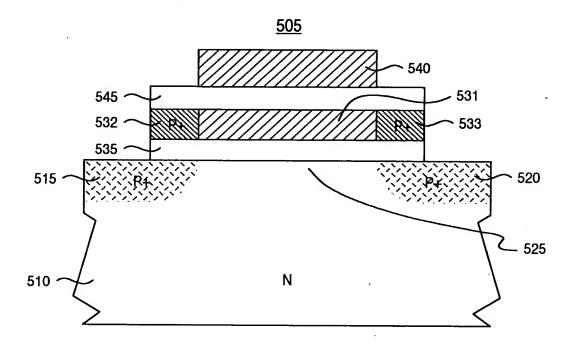


FIGURE 5